

# Medium power transistor (-32V, -2A)

### 2SB1188 / 2SB1182 / 2SB1240

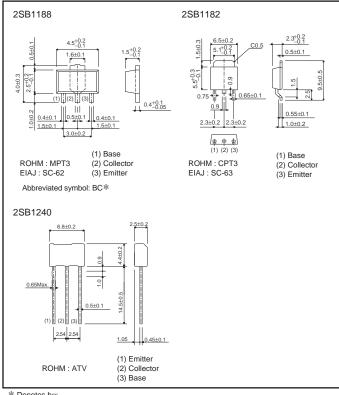
#### Features

- 1) Low VCE(sat).
  - VCE(sat) = -0.5V (Typ.)
  - $(I_{C}/I_{B} = -2A / -0.2A)$
- 2) Complements the 2SD1766 / 2SD1758 / 2SD1862.

#### Structure

Epitaxial planar type PNP silicon transistor

#### •Dimensions (Unit : mm)



\* Denotes her

#### •Absolute maximum ratings (Ta=25°C)

Para	ameter	Symbol	Limits	Unit	
Collector-base voltage		Vсво	-40	V	
Collector-emitter voltage		Vceo	-32	V	
Emitter-base voltage		Vево	-5	V	
		lc	-2	A(DC)	
Collector curren	t	IC	-3	A (Pulse)*1	
	2SB1188	Pc	0.5	W	
Collector power			2	W *2	
dissipation	2SB1182	FC	10	W (Tc=25°C)	
	2SB1240		1	W *3	
Junction temper	n temperature Tj 150 °		°C		
Storage tempera	ature	Tstg	–55 to 150	°C	

\*1 Single pulse, Pw=100ms

\*2 When mounted on a 40×40×0.7 mm ceramic board.

\*3 Printed circuit board, 1.7mm thick, collector copper plating 100mm<sup>2</sup> or larger.

#### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	-40	_	-	V	Ic=-50μA	
Collector-emitter breakdown voltage	BVCEO	-32	_	_	V	Ic=-1mA	
Emitter-base breakdown voltage	ВVево	-5	_	_	V	Iε= -50μA	
Collector cutoff current	Ісво	-	_	-1	μΑ	Vcb= -20V	
Emitter cutoff current	Іево	-	_	-1	μA	VEB=-4V	
Collector-emitter saturation voltage	VCE(sat)	-	-0.5	-0.8	V	Ic/I <sub>B</sub> = -2A/ -0.2A	*
DC current transfer ratio	hfe	120	_	390	-	Vce= -3V, Ic= -0.5A	*
Transition frequency	fт	_	100	_	MHz	Vce= -5V, Ie=0.5A, f=100MHz	
Output capacitance	Cob	-	50	-	pF	Vcb=-10V, Ie=0A, f=1MHz	

\* Measured using pulse current.

#### •Packaging specifications and hre

		Package		Taping	
		Code	T100	TL	TV2
Туре	hfe	Basic ordering unit (pieces)	1000	2500	2500
2SB1188	QR		0	-	_
2SB1182	QR		-	0	_
2SB1240	QR		_	-	0

hFE values are classified as follows :

Item	Q	R	
hfe	120 to 270	180 to 390	

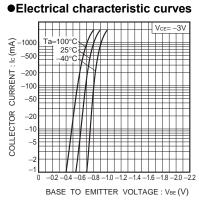
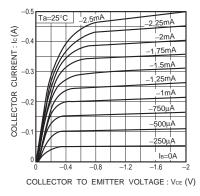
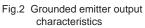
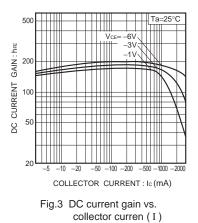


Fig.1 Grounded emitter propagation characteristics







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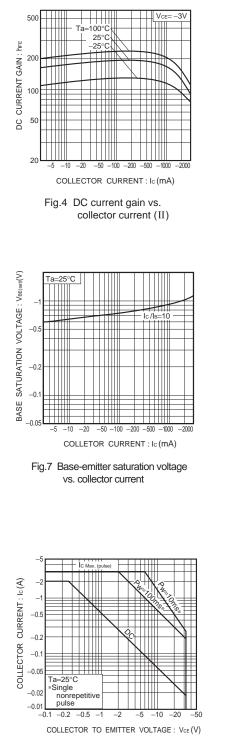
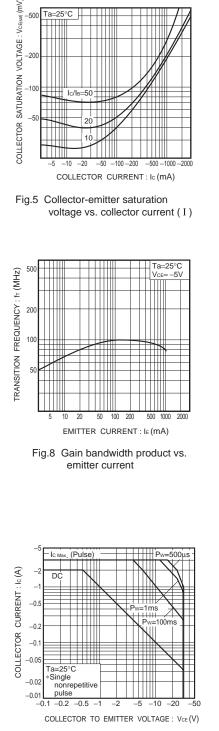
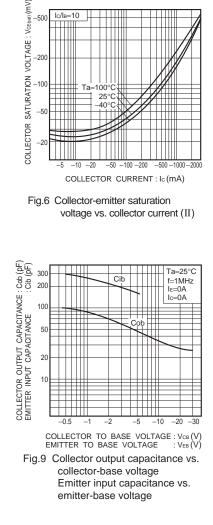


Fig.10 Safe operation area (2SB1188)



Ta=25°C

Fig.11 Safe operation area (2SB1182)



	Notes
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